2SC2590

Silicon NPN epitaxial planar type

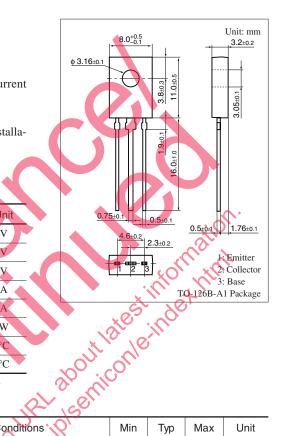
For low-frequency power amplification

■ Features

- \bullet Excellent collector current I_C characteristics of forward current transfer ratio h_{FE}
- High transition frequency f_T
- TO-126B package which requires no insulation plate for installation to the heat sink

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	120	V	
Collector-emitter voltage (Base open)	V _{CEO}	120	V	
Emitter-base voltage (Collector open)	V_{EBO}	V		
Collector current	Ic	0.5	A	
Peak collector current	I _{CP}	1.0	A	
Collector power dissipation	P_C	1.2	W	
Junction temperature	T_j	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	



■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

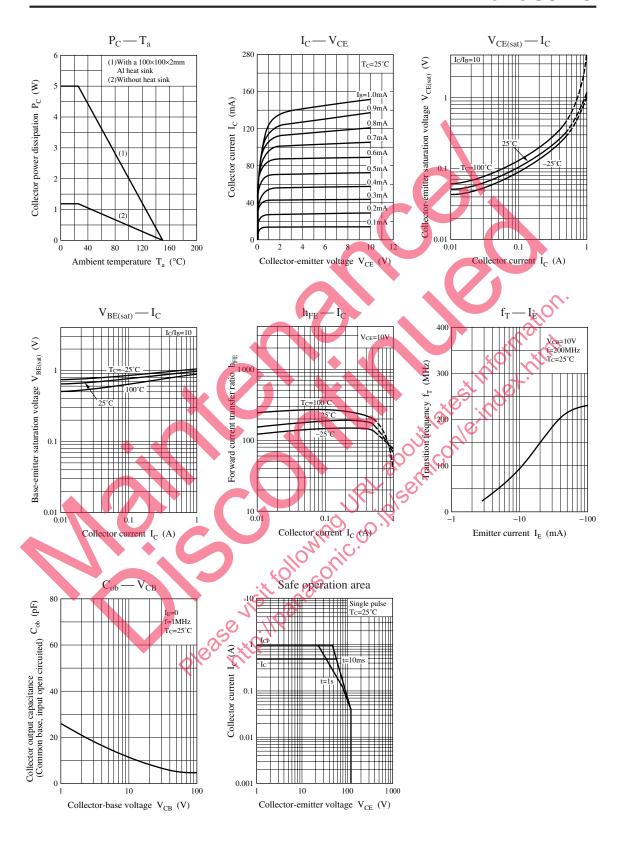
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 100 \mu A$ $I_{\rm B} = 0$	120			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_E = 10 \mu\text{A}$, $I_C = 0$	5			V
Forward current transfer ratio *1	h _{FE1} *2	V _{CH} 510 V, I _C = 150 mA	90		220	_
	h _{FE2}	$V_{CE} = 5 \text{ V} \cdot I_{C} = 500 \text{ mA}$	65	100		
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$			1.0	V
Base-emitter saturation voltage	VBE(sat)	$I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$			1.2	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		11	20	pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

Rank	Q	R
h_{FE1}	90 to 155	130 to 220



2 SJD00100BED

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